

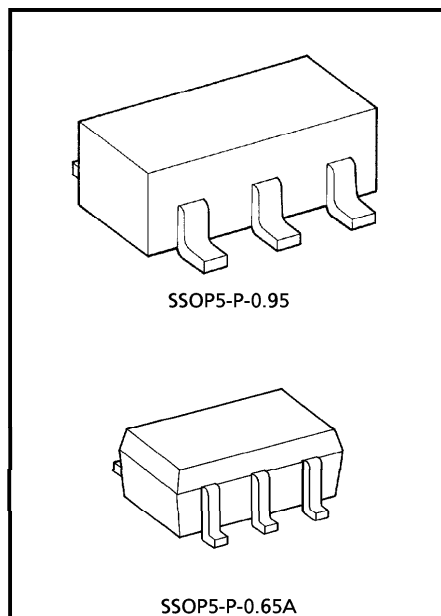
TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

**TC7SZ04F, TC7SZ04FU****INVERTER****FEATURES**

- High Output Drive :  $\pm 24$  mA (Typ.)  
@ $V_{CC} = 3$  V
- Super High Speed Operation :  $t_{PD}$  2.4 ns (Typ.)  
@ $V_{CC} = 5$  V, 50 pF
- Operation Voltage Range :  $V_{CC}$  (opr) = 1.8~5.5 V
- Supply Voltage Data Retention :  $V_{CC} = 1.5$ ~5.5 V
- 5 V Tolerant Function
- Matches the Performance of TC74LCX Series when  
Operated at 3.3 V  $V_{CC}$

**MAXIMUM RATINGS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~6	V
DC Input Voltage	$V_{IN}$	-0.5~6	V
DC Output Voltage	$V_{OUT}$	-0.5~6	V
Input Diode Current	$I_{IK}$	$\pm 20$	mA
Output Diode Current	$I_{OK}$	$\pm 20$	mA
DC Output Current	$I_{OUT}$	$\pm 50$	mA
DC $V_{CC}$ /Ground Current	$I_{CC}$	$\pm 50$	mA
Power Dissipation	$P_D$	200	mW
Storage Temperature	$T_{stg}$	-65~150	°C
Lead Temperature (10 s)	$T_L$	260	°C



Weight  
 SSOP5-P-0.95 : 0.016 g (Typ.)  
 SSOP5-P-0.65A : 0.006 g (Typ.)

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DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION		V <sub>CC</sub> (V)	Ta = 25°C			Ta = -40~85°C		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
High-Level Input Voltage	V <sub>IH</sub>			1.8	0.88	—	—	0.88	—	V
				2.3 – 5.5	0.75	—	—	0.75	—	
Low-Level Input Voltage	V <sub>IL</sub>			1.8	—	—	0.12	—	0.12	V
				2.3 – 5.5	—	—	0.25	—	0.25	
High-Level Output Voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	1.8	1.7	1.8	—	1.7	—	V
				2.3	2.2	2.3	—	2.2	—	
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I <sub>OH</sub> = -8 mA	2.3	1.9	2.15	—	1.9	—	
			I <sub>OH</sub> = -16 mA	3.0	2.4	2.8	—	2.4	—	
			I <sub>OH</sub> = -24 mA	3.0	2.3	2.68	—	2.3	—	
I <sub>OH</sub> = -32 mA	4.5	3.8	4.2	—	3.8	—				
Low-Level Output Voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OL</sub> = 100 μA	1.8	—	0	0.1	—	0.1	V
				2.3	—	0	0.1	—	0.1	
				3.0	—	0	0.1	—	0.1	
				4.5	—	0	0.1	—	0.1	
			I <sub>OL</sub> = 8 mA	2.3	—	0.1	0.3	—	0.3	
			I <sub>OL</sub> = 16 mA	3.0	—	0.15	0.4	—	0.4	
			I <sub>OL</sub> = 24 mA	3.0	—	0.22	0.55	—	0.55	
I <sub>OL</sub> = 32 mA	4.5	—	0.22	0.55	—	0.55				
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND	0 – 5.5	—	—	±1	—	±10	μA	
Power Off Leakage Current	I <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V	0.0	—	—	1	—	10	μA	
Quiescent Supply Current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	—	—	2	—	20	μA	

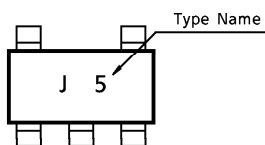
**AC ELECTRICAL CHARACTERISTICS** (Input  $t_r = t_f = 3 \text{ ns}$ )

CHARACTERISTIC	SYMBOL	TEST CONDITION	Ta = 25°C			Ta = -40~85°C		UNIT	
			VCC (V)	MIN.	TYP.	MAX.	MIN.		MAX.
Propagation Delay Time	tPLH	CL = 15 pF, RL = 1 MΩ	1.8	2.0	4.4	9.5	2.0	10.0	ns
			2.5 ± 0.2	0.8	2.9	6.5	0.8	7.0	
	3.3 ± 0.3		0.5	2.1	4.5	0.5	4.7		
	5.0 ± 0.5		0.5	1.8	3.9	0.5	4.1		
	tPHL		3.3 ± 0.3	1.5	2.9	5.0	1.5	5.2	
		CL = 50 pF, RL = 500 Ω	5.0 ± 0.5	0.8	2.4	4.3	0.8	4.5	
Input Capacitance	CIN		0 - 5.5	—	4	—	—	pF	
Power Dissipation Capacitance	CPD	(Note 1)	3.3	—	20	—	—	pF	
			5.5	—	26	—	—		

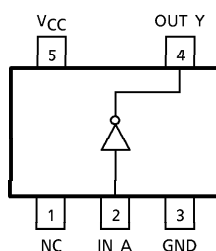
(Note 1)  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.  
Average operating current can be obtained by the equation.

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

**MARKING**



**PIN ASSIGNMENT (TOP VIEW)**



**TRUTH TABLE**

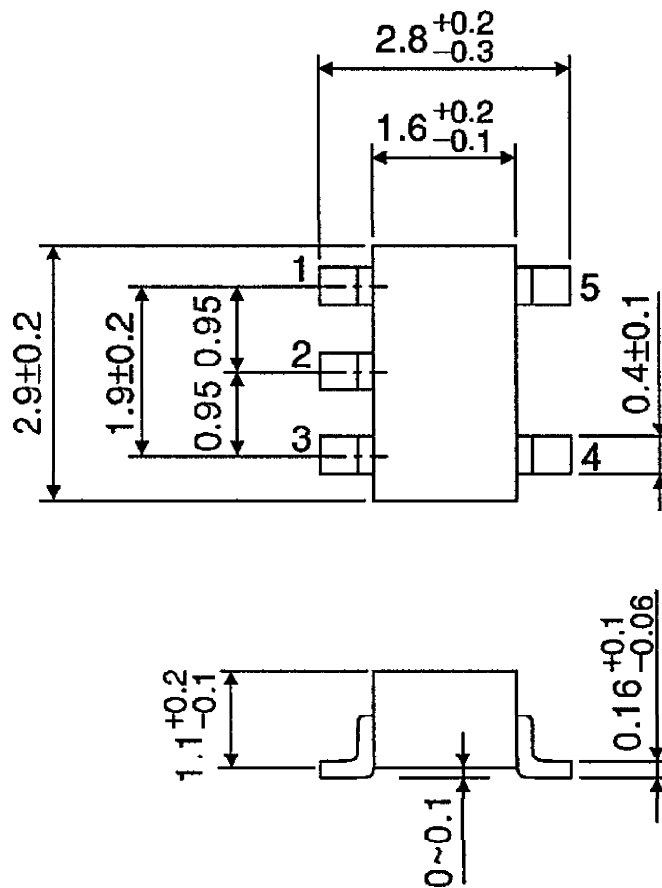
A	Y
L	H
H	L

**LOGIC DIAGRAM**



OUTLINE DRAWING  
SSOP5-P-0.95

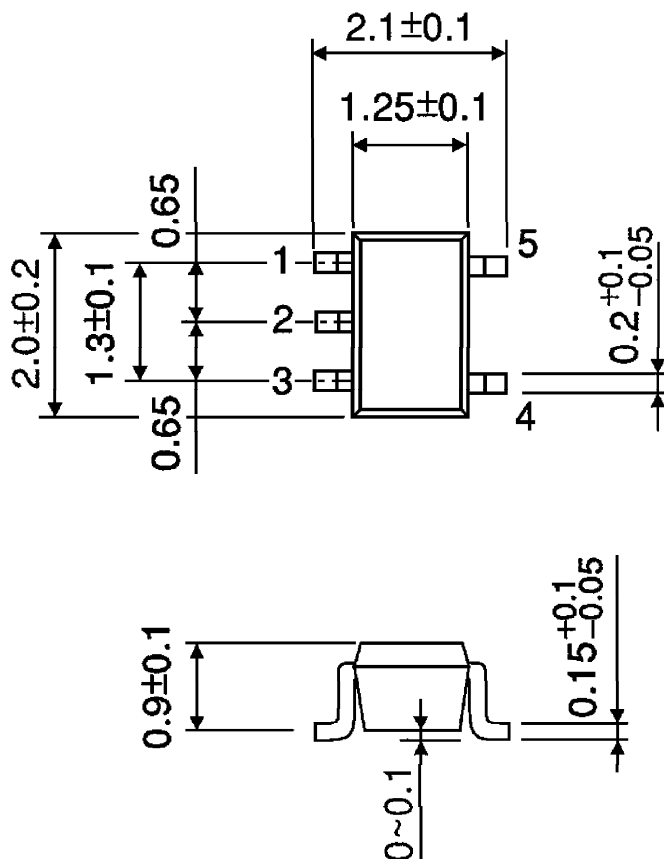
Unit : mm



Weight : 0.016 g (Typ.)

OUTLINE DRAWING  
SSOP5-P-0.65A

Unit : mm



Weight : 0.006 g (Typ.)